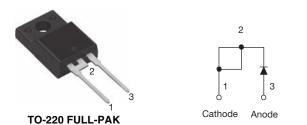
Vishay Semiconductors

# High Voltage, Input Rectifier Diode, 20 A



www.vishay.com

PRODUCT SUMMARY			
Package TO-220FP			
I <sub>F(AV)</sub>	20 A		
V <sub>R</sub>	800 V to 1200 V		
V <sub>F</sub> at I <sub>F</sub>	1.1 V		
I <sub>FSM</sub>	300 A		
T <sub>J</sub> max.	150 °C		
Diode variation	Single die		

### **FEATURES**

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47

Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)



- UL E78996 approved
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### APPLICATIONS

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

#### DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

OUTPUT CURRENT IN TYPICAL APPLICATIONS				
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS	
Capacitive input filter $T_A = 55 \text{ °C}$ , $T_J = 125 \text{ °C}$ common heatsink of 1 °C/W	18	22	А	

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UI		
I <sub>F(AV)</sub>	Sinusoidal waveform	20	А	
V <sub>RRM</sub>	Range	800/1200	V	
I <sub>FSM</sub>		300	А	
V <sub>F</sub>	10 A, T <sub>J</sub> = 25 °C	1.0	V	
TJ		-40 to +150	°C	

VOLTAGE RATINGS					
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA		
VS-20ETS08FPPbF, VS-20ETS08FP-M3	800	900	1		
VS-20ETS12FPPbF, VS-20ETS12FP-M3	1200	1300	1		



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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I <sub>F(AV)</sub>	$T_C = 51 \text{ °C}$ , 180° conduction half sine wave	20		
Maximum peak one cycle	1	10 ms sine pulse, rated $V_{\text{RRM}}$ applied	250	A	
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	300		
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t -	10 ms sine pulse, rated $V_{RRM}$ applied	316	– A <sup>2</sup> s	
		10 ms sine pulse, no voltage reapplied	442	A-2	
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V <sub>FM</sub>	20 A, T <sub>J</sub> = 25 °C		1.1	V
Forward slope resistance	r <sub>t</sub>	— T <sub>J</sub> = 150 °C		10.4	mΩ
Threshold voltage	V <sub>F(TO)</sub>			0.85	V
Maximum reverse leakage current	I	$T_J = 25 \text{ °C}$ $V_B = \text{Rated } V_{BBM}$	0.1	mA	
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	VR - naieu VRRM	1.0	ША

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperat	ture range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation	2.8	
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		62	°C/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth, and greased	0.5	
Approximate weight				2	g
				0.07	oz.
Mounting torque minimum maximum				6.0 (5.0)	kgf ⋅ cm
				12 (10)	(lbf · in)
Marking device				20ETS	S08FP
			Case style TO-220 FULL-PAK	20ETS	S12FP

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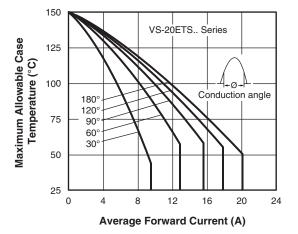


Fig. 1 - Current Rating Characteristics

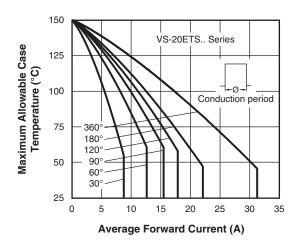


Fig. 2 - Current Rating Characteristics

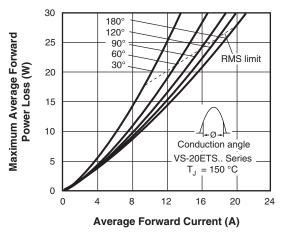


Fig. 3 - Forward Power Loss Characteristics

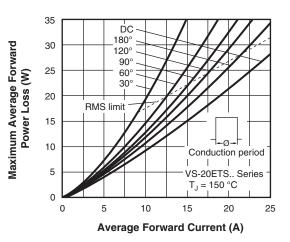
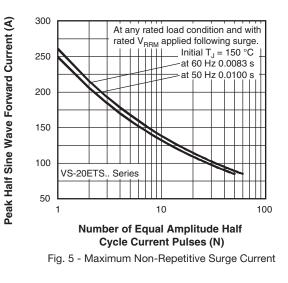
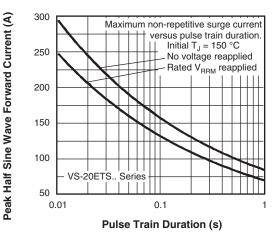


Fig. 4 - Forward Power Loss Characteristics







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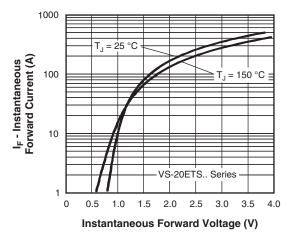


Fig. 7 - Forward Voltage Drop Characteristics

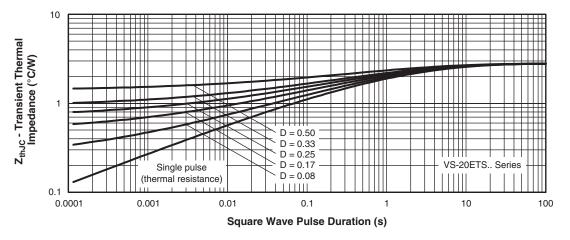


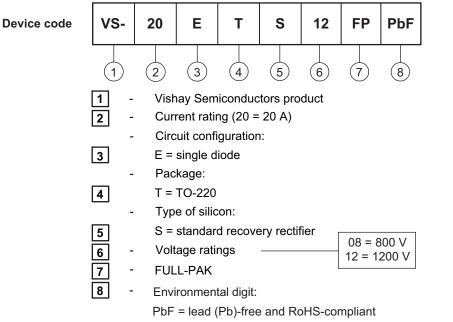
Fig. 8 - Thermal Impedance ZthJC Characteristics



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### **ORDERING INFORMATION TABLE**



-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-20ETS08FPPbF	50	1000	Antistatic plastic tubes		
VS-20ETS08FP-M3	50	1000	Antistatic plastic tubes		
VS-20ETS12FPPbF	50	1000	Antistatic plastic tubes		
VS-20ETS12FP-M3	50	1000	Antistatic plastic tubes		

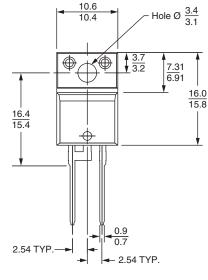
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95005</u>				
Dort moreling information	TO-220 FP PbF	www.vishay.com/doc?95009		
Part marking information	TO-220 FP -M3	www.vishay.com/doc?95440		



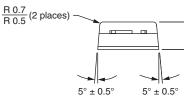
# **Outline Dimensions**

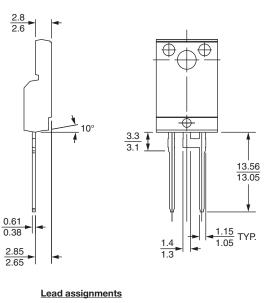
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### **DIMENSIONS** in millimeters



 $\frac{4.8}{4.6}$ 





<u>Diodes</u> 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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